

4V Drive Pch MOSFET

RRR030P03

Structure

Silicon P-channel MOSFET

●Features

- 1) Low On-resistance
- 2) Space saving-small surface mount package (TSMT3)
- 3) 4V drive

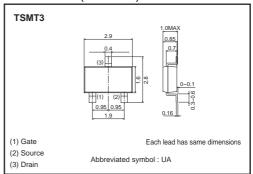
Applications

Switching

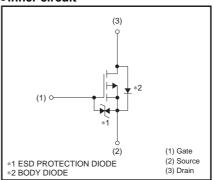
Packaging specifications

	Package	Taping	
Type	Code	TL	
	Basic ordering unit (pieces)	3000	
RRR030P03		0	

●Dimensions (Unit:mm)



●Inner circuit



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Drain-source voltage		V _{DSS}	-30	V
Gate-source voltage		V _{GSS}	±20	V
Droin augreent	Continuous	I _D	±3	Α
Drain current	Pulsed	I _{DP} *1	±12	Α
Source current	Continuous	Is	-0.8	А
(Body diode)	Pulsed	I _{SP} *1	-12	Α
Total power dissipation		Pp *2	1.0	W
Channel temperature		Tch	150	°C
Range of storage temperature		Tstg	-55 to +150	°C

^{*1} Pw≤10μs, Duty cycle≤1%

Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a)*	125	°C/W

^{*} When mounted on a ceramic board

^{*2} When mounted on a ceramic board

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●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	_	_	±10	μΑ	V _{GS} = ±20V, V _{DS} =0V
Drain-source breakdown voltage	V _(BR) DSS	-30	_	-	V	I _D = -1mA, V _{GS} =0V
Zero gate voltage drain current	IDSS	_	-	-1	μΑ	Vps= -30V, Vgs=0V
Gate threshold voltage	V _{GS (th)}	-1.0	-	-2.5	V	$V_{DS} = -10V, I_{D} = -1mA$
Static drain-source on-state resistance		_	55	75	mΩ	I _D = -3A, V _G S= -10V
	R _{DS (on)} *	_	85	115	mΩ	I _D = -1.5A, V _G S= -4.5V
		_	95	125	mΩ	ID= -1.5A, VGS= -4V
Forward transfer admittance	Y _{fs} *	2.4	_	-	S	V _{DS} = -10V, I _D = -3A
Input capacitance	Ciss	_	480	_	pF	V _{DS} = -10V
Output capacitance	Coss	_	70	_	pF	V _{GS} =0V
Reverse transfer capacitance	Crss	_	70	-	pF	f=1MHz
Turn-on delay time	t _{d (on)} *	_	7	_	ns	V _{DD} ≒ −15V
Rise time	tr *	_	18	_	ns	ID= -1.5A
Turn-off delay time	t _{d (off)} *	_	50	_	ns	VGS= −10V RL≒10Ω
Fall time	t _f *	_	35	_	ns	Rgs=10Ω
Total gate charge	Qg *	_	5.2	_	nC	V _{DD} ≒-15V, I _D =-3A
Gate-source charge	Q _{gs} *	_	1.6	_	nC	V _{GS} = -5V
Gate-drain charge	Q _{gd} *	_	1.6	_	nC	RL≒5Ω, R _G =10Ω

^{*}Pulsed

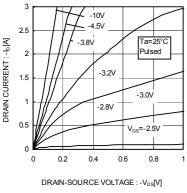
●Body diode characteristics (Source-drain) (Ta=25°C)

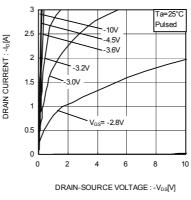
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp*	_	_	-1.2	V	I _S = -3A, V _{GS} =0V

^{*}Pulsed

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•Electrical characteristic curves





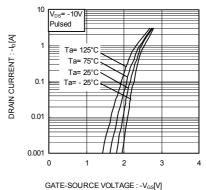
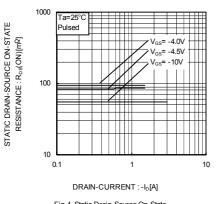


Fig.1 Typical output characteristics(I)

Fig.2 Typical output characteristics(II)

Fig.3 Typical Transfer Characteristics



V_{GS}= -10V
Pulsed
Ta=125°C
Ta=75°C
Ta=25°C
Ta=25°C
Ta=-25°C

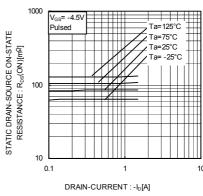
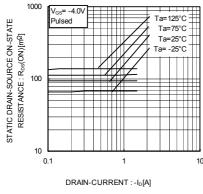
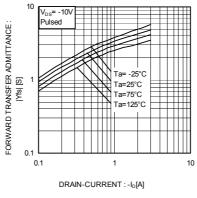


Fig.4 Static Drain-Source On-State
Resistance vs. Drain Current(I)

Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)





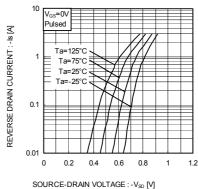
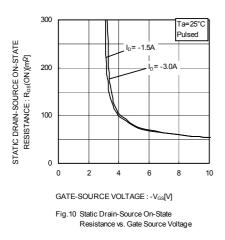
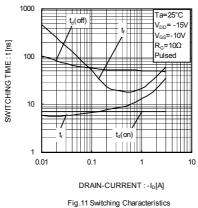


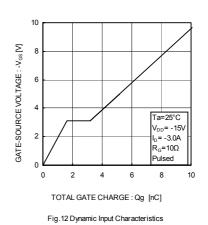
Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)

Fig.8 Forward Transfer Admittance
vs. Drain Current

Fig.9 Reverse Drain Current
vs. Sourse-Drain Voltage







Coss Ciss

100

Coss Ciss

Ciss

Ta=25°C

FallH1z

Vos=0V

DRAIN-SOURCE VOLTAGE: -V_{DS}[V]

Fig.13 Typical Capacitance vs. Drain-Source Voltage

●Measurement circuit

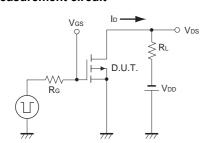


Fig.1-1 Switching Time Measurement Circuit

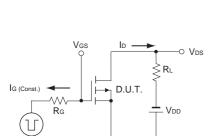


Fig.2-1 Gate Charge Measurement Circuit

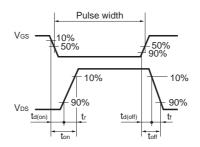


Fig.1-2 Switching Waveforms

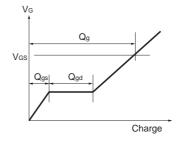


Fig.2-2 Gate Charge Waveform

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